TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

# TLP3051(S),TLP3052(S)

OFFICE MACHINE
HOUSEHOLD USE EQUIPMENT
TRIAC DRIVER
SOLID STATE RELAY

The TOSHIBA TLP3051(S) and TLP3052(S) consists of a photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

• Peak Off-State Voltage : 600V(Min)

• Trigger LED Current : 15mA(Max) (TLP3051(S))

10mA(Max) (TLP3052(S))

On-State Current : 100mA(Max)
 Isolation Voltage : 5000Vrms(Min)

• UL Recognized : UL1577,File No.E67349

• SEMKO Approved : SS EN60065

SS EN60950, File No.9841111

• BSI Approved : BS EN60065, File No.8385

BS EN60950, File No.8386

• Option (D4) type

VDE approved: DIN EN60747-5-2

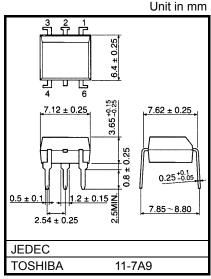
Approved No. 40009302

Maximum operating insulation voltage: 890VPK Highest permissible over voltage: 8000VPK

(Note):When a EN60747-5-2 approved type is needed, please designate the "Option (D4)"

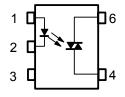
• Construction Mechanical Rating

	7.62 mm pich	10.16 mm pich			
	Standard Type	TLPxxxxF Type			
Creepage Distance Clearance Insulation Thickness	7.0 mm (Min) 7.0 mm (Min) 0.5 mm (Min)	8.0 mm (Min) 8.0 mm (Min) 0.5 mm (Min)			



Weight: 0.39 g (typ.)

## Pin Configuration (top view)



- 1: Anode
- 2: Csthode
- 3: N.C.
- 4:Terminal 1
- 6:Terminal 2



#### Absolute Maximum Ratings (Ta=25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT		
	Forward Current	lF	50	mA		
	Forward Current Derating (Ta≥53°C)	ΔI <sub>F</sub> /°C	-0.7	mA /°C		
LED	Peak Forward Current (100µs pulse, 100pps)		I <sub>FP</sub>	1	Α	
۳	Power Dissipation		$P_D$	100	mW	
	Power Dissipation Derating (Ta≥25°C)		ΔP <sub>D</sub> /°C	-1.0	mW/°C	
	Reverse Voltage		V <sub>R</sub>	5	V	
	Junction Temperature	Tj	125	°C		
	Off-State Output Terminal Voltage	$V_{DRM}$	600	V		
	On-State RMS Current	Ta=25°C	I <sub>T(RMS)</sub>	100	mA	
	On-State NWO Guirent	Ta=70°C	TI(RMS)	50		
70R	On-State Current Derating (Ta≥25°C)	ΔI <sub>T</sub> /°C	-1.1	mA /°C		
DETECTOR	Peak On-State Current (100µs pulse, 120pps)	I <sub>TP</sub>	2	Α		
E	Peak Nonrepetitive Surge Current (Pw=10ms,DC=10	I <sub>TSM</sub>	1.2	Α		
	Power Dissipation	P <sub>D</sub>	300	mW		
	Power Dissipation Derating (Ta≥25°C)	ΔP <sub>D</sub> /°C	-4.0	mW/°C		
	Junction Temperature		Tj	115	°C	
Stor	age Temperature Range	T <sub>stg</sub>	-55~150	°C		
Оре	rating Temperature Range	T <sub>opr</sub>	-40~100	°C		
Lea	d Soldering Temperature (10s)	T <sub>sol</sub>	260	°C		
Tota	al Package Power Dissipation	P <sub>T</sub>	330	mW		
Tota	al Package Power Dissipation Derating (Ta≥25°C)	ΔP <sub>T</sub> /°C	-4.4	mW /°C		
Isola	ation Voltage (AC,1min. , R.H.≤60%)	BVS	5000	Vrms		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 2) Device considered a two terminal device :Pins1, 2 and 3 shorted together and pin 4 and pin 6 shorted together.

#### **Recommended Operating Conditions**

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V_{AC}$	_	_	240	$V_{\text{ac}}$
Forward Current	I <sub>F</sub> *	15	20	25	mA
Peak On-State Current	I <sub>TP</sub>	_	_	1	Α
Operating Temperature	T <sub>opr</sub>	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

<sup>\*</sup>In The case of TLP3052



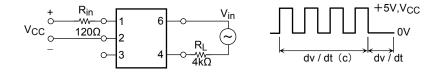
## Individual Electrical Characteristics (Ta=25°C)

CHARACTERISTIC SYMBOL		TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μA
	Capacitance	Ст	V = 0, f=1MHz	_	30	_	pF
22	Peak Off-State Current	I <sub>DRM</sub>	V <sub>DRM</sub> =600V	_	10	1000	nA
0 1	Peak On-State Voltage	$V_{TM}$	I <sub>TM</sub> =100mA	_	1.7	3.0	V
ပ	Holding Current	I <sub>H</sub>	_	_	1.0	_	mA
ΗE	Critical Rate of Rise of Off-State Voltage	dv/dt	Vin=240Vrms , Ta=85°C (Fig.1)	_	500	_	V/µs
D E	Critical Rate of Rise of Commutating Voltage	dv/dt(c)	Vin=60Vrms , IT=15mA (Fig.1)	_	0.2	_	V/µs

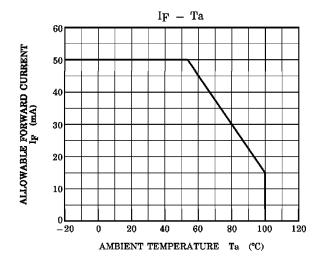
## Coupled Electrical Characteristics (Ta=25°C)

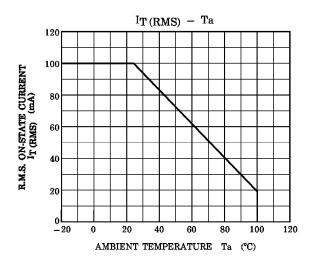
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	TLP3051(S)	- I <sub>FT</sub>	V <sub>T</sub> =6V	_	_	15	mA
	TLP3052(S)			_	5	10	
Capacitance (Input to C	apacitance (Input to Output)		VS=0 , f=1MHz	_	0.8	_	pF
Isolation Resistance		Rs	VS=500V(R.H.≤60%)	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
Isolation Voltage		BVs	AC , 1minute	5000	_	_	Vrms
			AC , 1second,in oil	_	10000	_	
			DC , 1minute,in oil		10000		Vdc

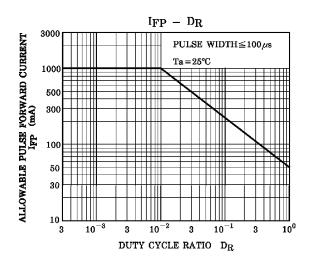
Fig. 1 dv / dt test circuit

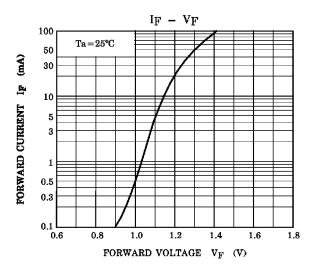


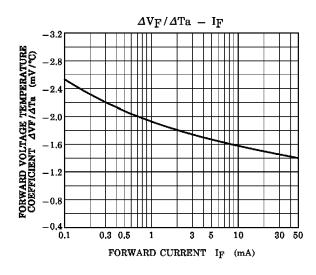
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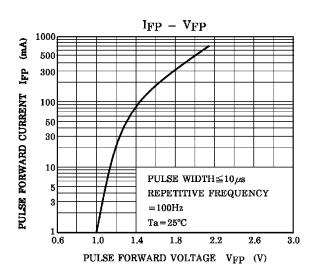




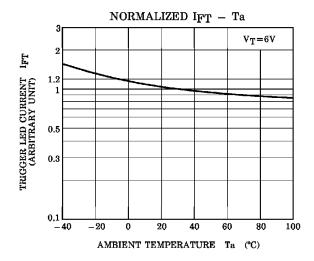


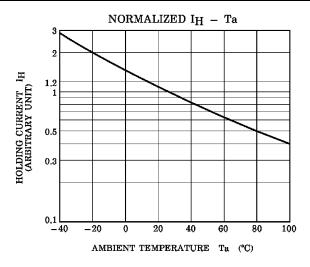


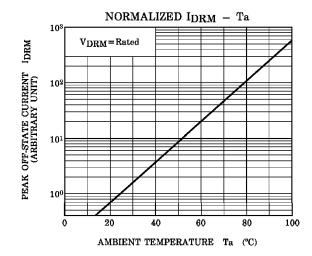


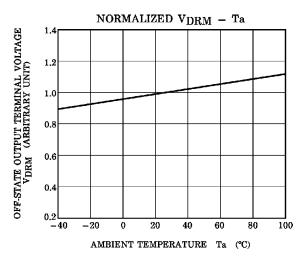


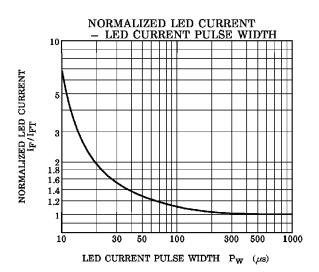
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